

Features

- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Multilayer Metal -Silicon Potential Structure.
- Low Power Loss, High Efficiency
- High Surge Capacity and High Current Capability
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Lead Free Finish/RoHS Compliant(Note 1) ("P" Suffix Designates Compliant. See Ordering Information)
- High Junction Temperature Capability

Maximum Ratings

- Operating Junction Temperature Range: -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Typical Thermal Resistance: 0.5°C/W Junction to Case

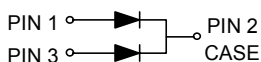
MCC Part Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
MBR30150PT	MBR30150PT	150V	105V	150V

Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	30A	$T_C=125^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	275A	8.3ms, Half Sine Wave
Instantaneous Forward Voltage	V_F	0.87V(Max) 0.83V(Typ) 0.80V(Max)	$I_{FM}=15\text{A}; T_J=25^\circ\text{C}$ $I_{FM}=15\text{A}; T_J=125^\circ\text{C}$
Maximum Reverse Current at Rated DC Blocking Voltage	I_R	0.01mA 1.5mA	$T_J=25^\circ\text{C}$ $T_J=125^\circ\text{C}$

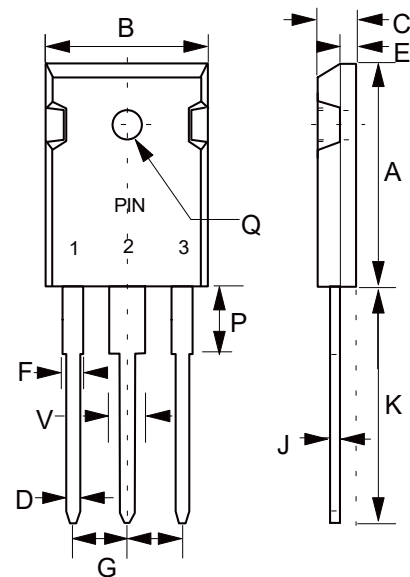
Note:1. High Temperature Solder Exemptions Applied, see EU Directive Annex 7a.

Internal Structure:



**30 Amp
Schottky
Barrier Rectifier
150 Volts**

TO-247



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.787	0.866	20.00	22.00	
B	0.598	0.638	15.20	16.20	
C	0.185	0.208	4.70	5.30	
D	0.035	0.059	0.90	1.50	
E	0.059	0.094	1.50	2.40	
F	0.067	0.091	1.70	2.30	
J	0.019	0.031	0.48	0.80	
K	0.748	0.833	19.00	21.15	
P	0.122	0.189	3.10	4.80	
Q	0.118	0.150	3.00	3.80	Φ
V	0.106	0.134	2.70	3.40	
G	0.197	0.224	5.00	5.70	

Curve Characteristics

Fig. 1 - Forward Current Derating Curve

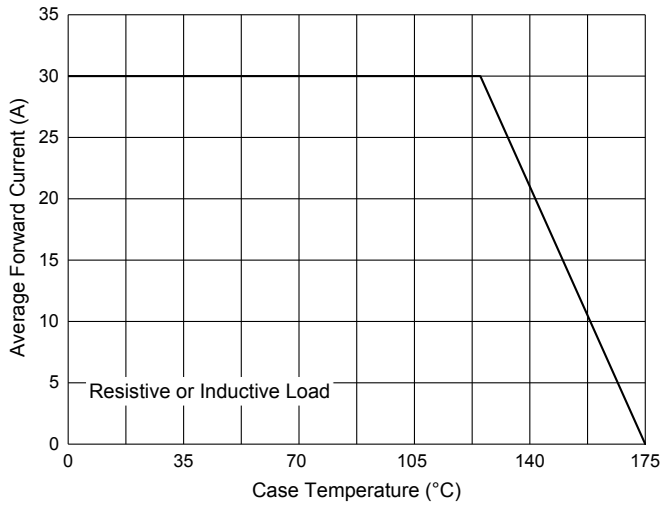


Fig. 2 - Typical Instantaneous Forward Characteristics

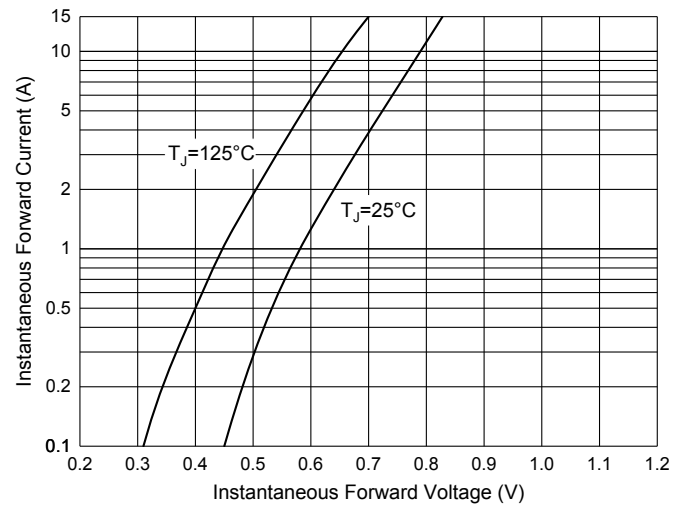


Fig. 3 - Typical Reverse Leakage Characteristics

